



Exchange biasing in SFMO/SFWO double perovskite multilayer thin films

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ABSTRACT

In the present study, we have studied the exchange bias interaction in ferromagnetic $\text{Sr}_2\text{FeMoO}_6$ (SFMO)/antiferromagnetic Sr_2FeWO_6 (SFWO) multilayer thin films deposited on single crystal LaAlO_3 substrates using KrF pulsed laser deposition technique. XRD pattern revealed that SFMO, SFWO and their multilayer thin films were highly oriented along the c -axis. The microstructure studied by atomic force microscopy was found to be uniform, fine, dense and homogenous in nature. The observed magnetization-temperature curves showed Neel temperature $T_N \sim 37$ K for SFWO and Curie temperature $T_C > 320$ K for SFMO thin films. For multilayer, the field cooled magnetization–field curve was shifted horizontally and the direction of the horizontal shift is opposite to that of H_{FC} , indicating an exchange bias effect. Exchange bias field H_E was found to decrease with increase in temperature and approached to zero at blocking temperature.

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1. Introduction

Exchange bias effect between ferromagnetic (FM) and antiferromagnetic (AFM) material was discovered in 1956 by Meiklejohn and Bean [1]. Although there has been some research in exchange bias of nanoparticles in the last decades, the bulk of exchange bias research remained focused mainly on thin film systems [2,3]. When a FM/AFM multilayer thin film is cooled through the Neel temperature (T_N) of antiferromagnetic material (T_N less than T_C , the curie temperature of the ferromagnetic material), the hysteresis loop of FM is now shifted or biased away from the origin. This shift is known as the exchange field (H_E), can be several hundreds Oersted in size. Antiferromagnetic layers are an important component of hard disk read heads and of non-volatile magnetic random access memory elements, MRAM. The effect of exchange bias at the interface between an antiferromagnetic (AFM) and a ferromagnetic (FM) layer expresses itself as a unidirectional pinning or anisotropy of the magnetization of the ferromagnet, and is utilized to fix the magnetization in a magnetic reference layer in a spin-valve structure or a magnetic tunnel junction (MTJ), which consists of two ferromagnetic layers separated by a non-magnetic metal (spin-valve) or an insulator (MTJ) [4–12].

The ideal structure of double perovskite materials can be viewed as a regular arrangement of corner-sharing BO_6 and $\text{B}'\text{O}_6$ octahedra, alternating along the three direction of crystal, with A cation occupying the voids in between the octahedra. The crystal structure and physical properties of double perovskite oxides

($\text{A}_2\text{BB}'\text{O}_6$) depend considerably on the size and valences of A, B and B' cations. For instance, in $\text{Sr}_2\text{FeMoO}_6$ compound, the localized and coupled Fe spins of the Fe–O–Mo–O–Fe network through Mo 4d conduction electrons, give rise to a metallic ferromagnetic ($T_C \sim 420$ K) ground state [13–16]. Interestingly in the same line Sr_2FeWO_6 is an anti-ferromagnetic (AFM) insulator with a low Neel temperature ($T_N \sim 37$ K) as Fe–O–W–O–Fe network enhances super-exchange coupling [17–19]. The origin of such a different behavior is mainly due to the 2p(O)–5d(W) orbital hybridization in Sr_2FeWO_6 compound, being stronger than the 2p(O)–4d(Mo) hybridization in $\text{Sr}_2\text{FeMoO}_6$ compound [20], which in turn pushes the 5d(W) band toward higher energies producing an insulating ground state and thereby inhibiting the ferromagnetic interaction active in $\text{Sr}_2\text{FeMoO}_6$ compound [21,22]. Both the FM SFMO and AFM SFWO compositions exhibit tetragonally distorted perovskite structure with lattice mismatch of about 0.8% and are chemically compatible. The small mismatch and the chemical compatibility between the FM and AFM layers allow the growth of epitaxial heterostructures with almost atomically perfect interfaces.

The main objective of the present study is to fabricate the high quality SFMO, SFWO and $[\text{SFMO} (100 \text{ \AA})/\text{SFWO} (40 \text{ \AA})]_{15}$ multilayer thin films and to examine the effect of temperature on exchange bias. To the best of our knowledge, there is no report on SFMO/SFWO multilayer thin films in literature. The values of the exchange field H_E and coercivity H_C , as a function of temperature, were measured and the blocking temperature was found.

2. Experimental

SFWO, SFMO and $[\text{SFMO} (100 \text{ \AA})/\text{SFWO} (40 \text{ \AA})]_{15}$ were fabricated on single crystalline LaAlO_3 substrate using multitarget pulsed laser deposition technique (Excel instruments, India). In order to synthesize the multilayer structure, SFMO and SFWO

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targets were mounted on a step-motor controlled rotatable carrier which allowed different targets to be sequentially exposed to the beam paths. To ablate sintered pellet targets, a pulsed laser beam generated by a KrF excimer laser (Lambda Physik) at a wavelength of 248 nm and pulse duration of 25 ns was introduced into the deposition chamber through a quartz window and focused using an optical lens onto the target surface. No external field was applied during deposition. Before every deposition, the targets were pre-ablated for 1 min in order to ascertain the same state of the target in every deposition. For removing magnetic contamination, the LaAlO_3 substrates were cleaned sequentially with concentrated HCl solution and trichloro ethylene, and then rinsed with deionized water. The substrate size was taken $5 \times 5 \text{ mm}^2$ which is smaller than the confined plume of our PLD, ensuring that there is no thickness gradient across the sample. The thickness of the films was measured using surface profiler and was kept constant for SFWO and SFMO thin films at approx. 220 nm. In case of multilayer, first layer of SFWO (40 Å) was deposited on the substrate followed by SFMO (100 Å) layer. In the present work, fifteen such bi-layers were deposited so the total thickness of multilayer was approx. 210 nm.

The orientation & crystallinity of these films were investigated using Bruker AXS D-8 advanced diffractometer of $\text{Cu K}\alpha$ (1.54 Å) in θ - 2θ geometry. To obtain a profile fitting with good signal, polycrystalline silicon powder was used for instrumental correction. Atomic force microscopy (NT-MDT: NTEGRA Model) was used in contact mode to study the surface morphology of these films. The root-mean-square roughness (R_{rms}) and average roughness (R_{avg}) of the surface was calculated three times at a different spot for each sample by AFM scan over $(2 \times 2) \mu\text{m}^2$ scanning area. For the exchange bias study, samples were heated to temperature of 320 K and cooled down to 5 K in the field of 1 T applied parallel to film surface [23]. Magnetic properties of the samples were characterized using superconducting quantum interference device (quantum design) in an applied magnetic field of ± 7 T.

3. Results and discussion

3.1. Structural properties

Fig. 1 shows the high angle X-ray diffraction pattern of SFWO, SFMO and $[\text{SFMO/SFWO}]_{15}$ multilayer thin film at room temperature deposited on LaAlO_3 substrate at fixed deposition temperature and pressure of 825°C and 2×10^{-5} Torr, respectively. It was observed that all these films exhibit only diffraction peaks corresponding to (001) reflections and the substrate, suggesting that the films were highly oriented along the c -axis, perpendicular to the growth. A small reflection corresponding to (101) plane at $2\theta = 19.6^\circ$ was also observed (inset of Fig. 1) depicting the ordering of Fe/Mo ions at the B/B' sites in these films [24]. Therefore the films are textured [25]. The crystallite size of these films was calcu-

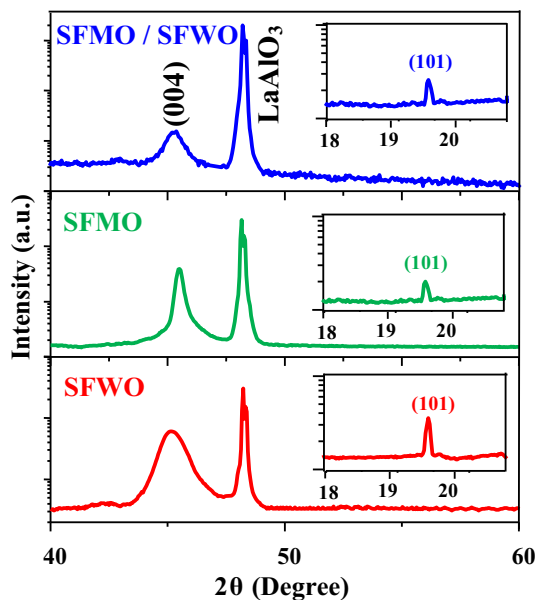


Fig. 1. High angle X-ray diffraction pattern of SFWO, SFMO and $[\text{SFMO/SFWO}]_{15}$ multilayer thin films. The inset shows the order-related diffraction peak of (101) plane.

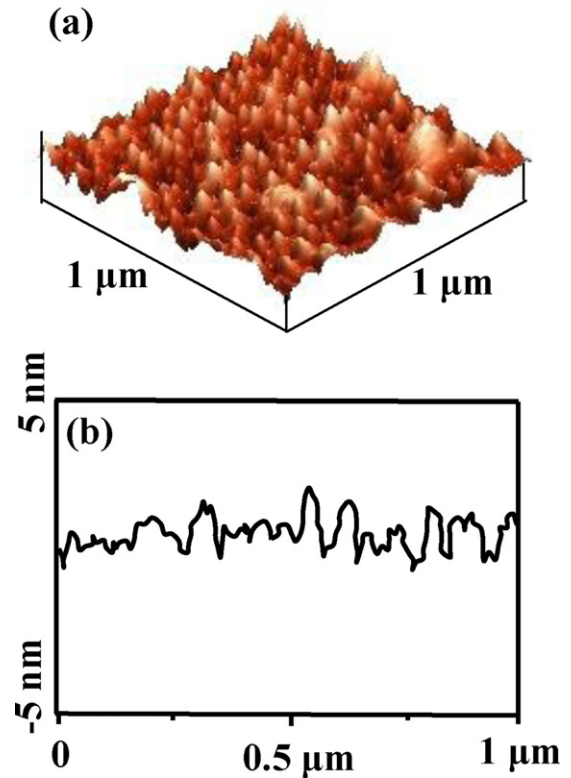


Fig. 2. Three-dimensional atomic force microscopy image and line scan of the surface of $[\text{SFMO/SFWO}]_{15}$. Scan was done over a $1 \mu\text{m}$ square area of the sample in contact mode.

lated using Scherrer's formula and was found to be 10.1, 27.5 and 12.2 nm for SFWO, SFMO and $[\text{SFMO/SFWO}]_{15}$, respectively.

Fig. 2 shows the 3D atomic force microscopy microstructure and line scan of the surface of multilayer thin film. The microstructure was found to be uniform, fine, dense and homogenous in nature. Atomic force microscopy was used to estimate the grain size, average roughness and root-mean-square roughness. The average roughness (R_{avg}) and root-mean-square roughness (R_{rms}) are defined from the following relationships: [26]

$$R_{\text{avg}} = \frac{1}{N} \sum_{i=1}^N |Z_i - \bar{Z}| \quad (1)$$

$$R_{\text{rms}} = \frac{1}{N} \left[\sum_{i=1}^N |Z_i - \bar{Z}|^2 \right]^{1/2} \quad (2)$$

where N is the number of surface height data and \bar{Z} the mean-height distance. The value of grain size, average roughness and root-mean-square roughness was found to be 19 nm, 1 nm and 1.4 nm, respectively.

The overall particle size shown by AFM was much bigger than that calculated by XRD, which is ascribed to the fact that AFM shows agglomeration of the particles whereas XRD gives an average mean crystallite size. The XRD and AFM data can be reconciled by the fact that smaller primary particles have a large surface free energy and would, therefore, tend to agglomerate faster and grow into larger grains.

3.2. Magnetic properties

Magnetic properties of these multilayers were measured using a SQUID magnetometer. The magnetization data for all the films

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